

**Technical Data** Data Sheet N1169, Rev. - **Green Products** 

# 129NQ135/R-1 129NQ150/R-1 SCHOTTKY RECTIFIER

### Applications:

• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

#### Features:

- 175℃ T<sub>J</sub> operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5'S
- Easier to mount and lower profile than DO-5'S
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- **High frequency operation**
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# CATHODE ANODE

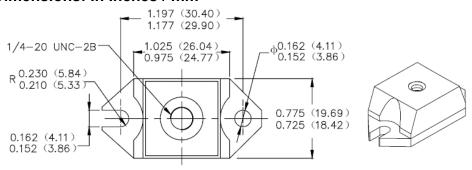
129NQ135-1

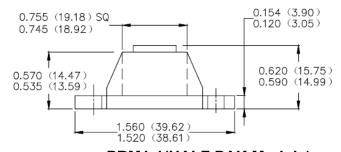
ANODE

129NQ135R-1

CATHODE

#### **Mechanical Dimensions: In Inches / mm**





## PRM1-1(HALF PAK Module)

#### MARKING.MOLDING RESIN

Marking for 129NQ135(150)/R-1, 1st row SS YYWWL, 2nd row 129NQ135(150)-1/129NQ135(150)R-1 Where YY is the manufacture year WW is the manufacture week code L is the wafer's Lot Number

Molding resin

Epoxy resin UL:94V-0

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# **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage	$V_{RRM}$	-	135	129NQ135(R)-1	V
Working Peak Reverse Voltage  DC Blocking Voltage	$V_{RWM}$		150	129NQ150(R)-1	
DC Blocking voltage	$V_R$				
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =110°C, rectangular wave form	120		A
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse		1140	А

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	$V_{F1}$	@ 120A, Pulse, T <sub>J</sub> = 25 °C	1.07	V
	$V_{F2}$	@ 120A, Pulse, T <sub>J</sub> = 125 °C	0.74	V
Max. Reverse Current (per	I <sub>R1</sub>	$@V_R = \text{rated } V_R T_J = 25  ^{\circ}\text{C}$	3	mA
leg) *	I <sub>R2</sub>	$@V_R = \text{rated } V_R T_J = 125  ^{\circ}\text{C}$	45	mA
Max. Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C$ $f_{SIG} = 1MHz$	3000	pF
Typical Series Inductance (per leg)	L <sub>S</sub>	Measured lead to lead 5 mm from package body	6.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

<sup>\*</sup>Pulse Width < 300µs, Duty Cycle <2%

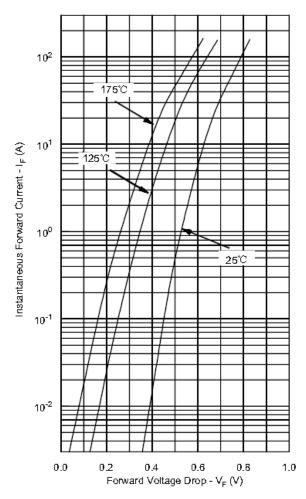
# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specific	Units		
Max. Junction Temperature	TJ	-	-55 to -	°C		
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +175		°C	
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	0.40		°C/W	
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.15		°C/W	
Mounting Torque	Тм	Non-lubricated threads	Mounting Torque Terminal Torque	23(min) 29(max) 35(min) 46(max)	Kg-cm	
Approximate Weight	wt	-	25.	g		
Case Style	PRM1-1					

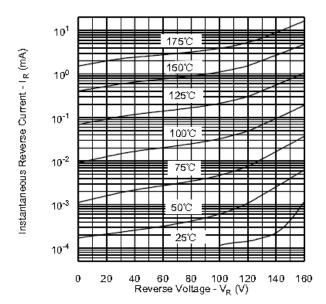


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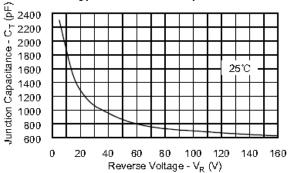
#### **Typical Forward Characteristics**



### Typical Reverse Characteristics



#### Typical Junction Capacitance



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#### **129NQ...R-1 SERIES**

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